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Preliminary



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## LV8011V — Bi-CMOS IC Forward/Reverse Motor Driver

### Overview

LV8011V is a 1ch forward/reverse motor driver IC using D-MOS FET for output stage. As MOS circuit is used, it supports the PWM input. Its features are that the on resistance ( $0.37\Omega$  typ) and current dissipation are low.

It also provides protection functions such as heat protection circuit and reduced voltage detection and is optimal for the motors that need high-current (maximum peak current : 5A).

### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$ , SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Power Source Voltage (For load)	VM max		-0.5 to 7.5	V
Maximum Power Source Voltage (For control)	V <sub>CC</sub> max		-0.5 to 6.0	V
Maximum Output Current	I <sub>O</sub> max	DC	1.0	A
	I <sub>O</sub> peak1	$t \leq 100\text{ms}$ , $f = 2\text{Hz}$	3.0	A
	I <sub>O</sub> peak2	$t \leq 10\text{ms}$ , $f = 2\text{Hz}$	5.0	A
Input Voltage	V <sub>IN</sub> max		-0.5 to V <sub>CC</sub> +0.5	V
Operating Temperature	T <sub>opr</sub>		-20 to +75	°C
Storage Temperature	T <sub>stg</sub>		-55 to 150	°C
Allowable Power Dissipation	P <sub>d</sub>	*Specified substrate	800	mW

\* When mounting the glass epoxy substrate 30mm×50mm×1.6mm.

### Allowable Operating Range at SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power Source Voltage (For load)	VM		2.0 to 6.5	V
Power Source Voltage (For control)	V <sub>CC</sub>		4.5 to 5.5	V
Input Signal Voltage	V <sub>IN</sub>		0 to V <sub>CC</sub>	V
Input Signal Frequency	f max	duty = 50%	100	kHz
Charge-Pump Capacitor	C1, C2, C3		0.001 to 0.1	μF

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## LV8011V

**Electric Characteristics** at  $T_a = 25^\circ\text{C}$ ,  $V_{CC} = V_M = 5.0\text{V}$ ,  $\text{SGND} = \text{PGND} = 0\text{V}$

Parameter	Symbol	Conditions	Ratings			Unit	Remarks
			min	typ	max		
Standby Power Source Current for Load	IMO	EN = 0V			1.0	$\mu\text{A}$	1
Standby Power Source Current for Control	ICO	EN = 0V, IN1 = IN2 = TIN = 5V		50	100	$\mu\text{A}$	2
Operating Current Consumption	IC1	EN = 5V, VG when non-load.		0.7	1.2	mA	3
High Level Input Voltage	$V_{IH}$		2.5		$V_{CC}$	V	
Low Level Input Voltage	$V_{IL}$		0		0.8	V	
High Level Input Current (IN1, IN2)	$I_{IH}$				1.0	$\mu\text{A}$	4
Low Level Input Current (IN1, IN2)	$I_{IL}$		-1.0			$\mu\text{A}$	
Pull-up Resistance Value (EN, TIN)	RUP		50	100	200	$\text{k}\Omega$	
Output ON Resistance	RON	Sum of top and bottom of ON resistance value.		0.37	0.60	$\Omega$	5
Charge-Pump Voltage	VG		9.5	10.4	11	V	6
Low Voltage Detection Operating Voltage	VCS	$V_{CC}$ Voltage	2.3	2.5	2.7	V	7
Thermal Shutdown Operating Temperature	TTSD	*Design Target	150	180	210	$^\circ\text{C}$	8
Charge-Pump Capacity (IG = 500 $\mu\text{A}$ )	VGLOAD		9.0	9.9		V	9
IG Current Dissipation (Fin = 20kHz)	IG				350	$\mu\text{A}$	10
Charge Pump Start-up Time	TVG	C1 = C2 = 0.01 $\mu\text{F}$ , CVG = 0.1 $\mu\text{F}$		0.5	1.0	ms	11
[Output Part]							
Turn-ON Time	TPLH			0.9	2.0	$\mu\text{s}$	12
Turn-OFF Time	TPHL			0.3	2.0	$\mu\text{s}$	12
[TOUT]							
Turn-ON Time	TOUT	C = 500pF		5.0	20	$\mu\text{s}$	12
Turn-OFF Time	TOFF	C = 500pF		5.0	20	$\mu\text{s}$	12

\* It is a design target value and measurement is not carried out.

### Remarks

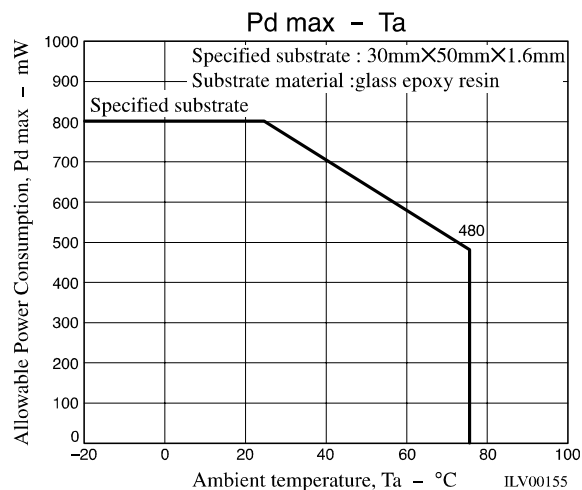
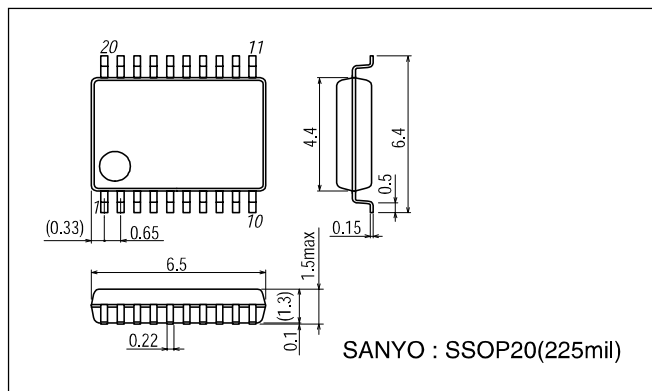
1. It shows current dissipation of VM pin in output OFF state.
2. It shows current dissipation of  $V_{CC}$  pin in stand-by state.  
(The standard current depends on EN pin pull-down resistance.)
3. It shows current dissipation of  $V_{CC}$  pin in state of EN = 5V (stand-by), including current dissipation of VG pin.
4. For IN1 and IN2 pins, no pull-down and pull-up resistance is needed. (High impedance pin)
5. It shows sum of upper and lower saturation voltages of OUT pin.
6. It controls charge-pump oscillation and makes specified voltage.
7. When low voltage is detected, the lower output is turned OFF.
8. When thermal protection circuit is activated, the lower output is turned OFF.  
When the heat temperature is fallen, it is turned ON again.
9. IG (VG pin load current) = 500 $\mu\text{A}$
10. It shows VG pin current dissipation in state of PWM input for IN pin.
11. It specifies start-up time from 10% to 90% when VG is in non-load state  
(when setting the capacitor between VG and GND to 0.1 $\mu\text{F}$  and  $V_{CC}$  is 5V).
12. It specifies 10% to 90% for start-up and 90% to 10% for shut-down.

## LV8011V

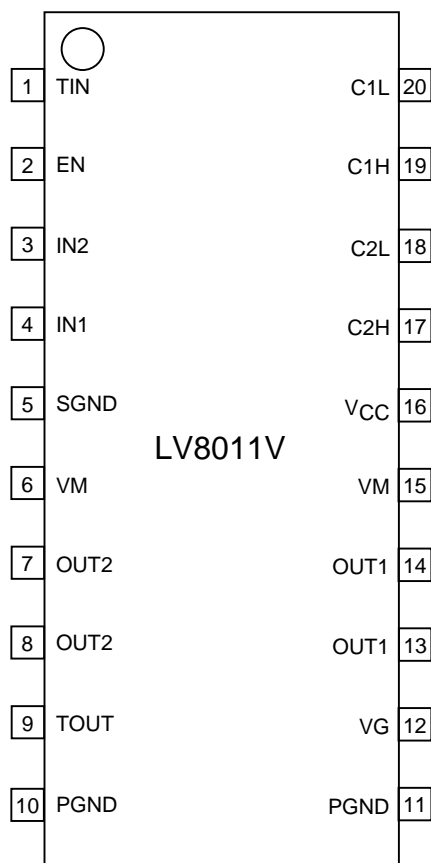
### Package Dimensions

unit : mm

3179B



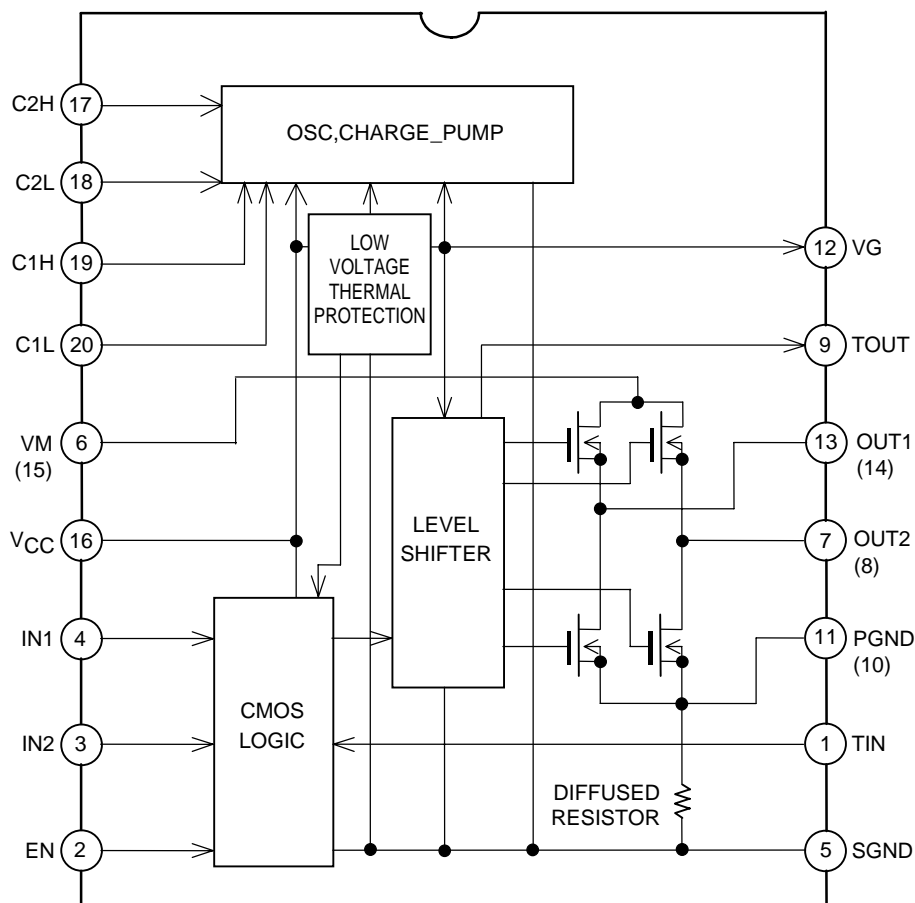
### Pin Assignment



Top view

## LV8011V

### Block Diagram



### True Value Table

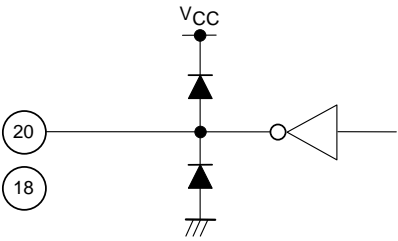
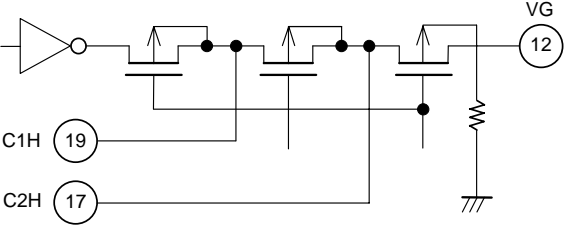
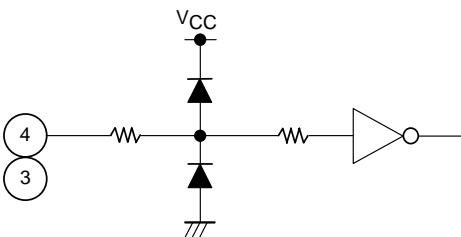
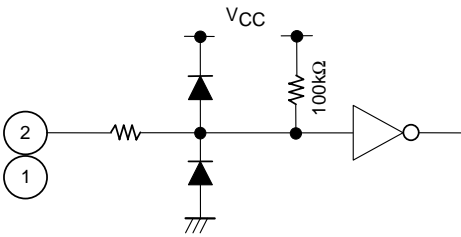
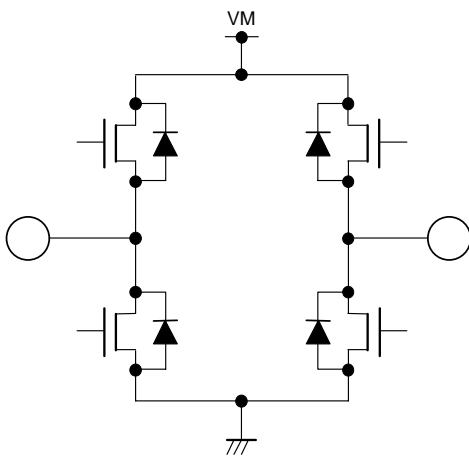
Z : High-Impedance - : Don't care

EN	IN1	IN2	TIN	OUT1	OUT2	TOUT	Mode
H	H	H	-	L	L	-	Brake
H	H	L	-	H	L	-	Forward evolution
H	L	H	-	L	H	-	Reverse rotation
H	L	L	-	Z	Z	-	Stand by
L	-	-	-	L	L	L	Stdbby
H	-	-	H	-	-	L	TR-OFF
H	-	-	L	-	-	H	TR-ON

\* For reduced voltage and thermal protection, the lower output is turned OFF and the motor drive stops.

## LV8011V

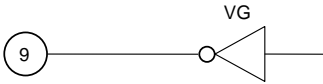
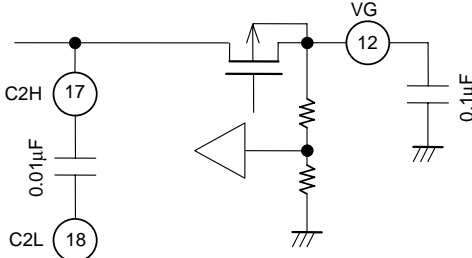
### Pin Description

Pin no.	Pin name	Equivalent Circuit	Pin Explanation
20 18	C1L C2L		Step-up Capacitor Connection Pin
19 17	C1H C2H		Step-up Capacitor Connection Pin
4 3	IN1 IN2		Driver Output Switch
2 1	EN TIN		Logic Enable Pin TOUT Output Control Pin (Built-in Pull-up Resistance)
13 14  7 8	OUT1   OUT2		Driver Output Pin (Both 2 pins are Connected.)

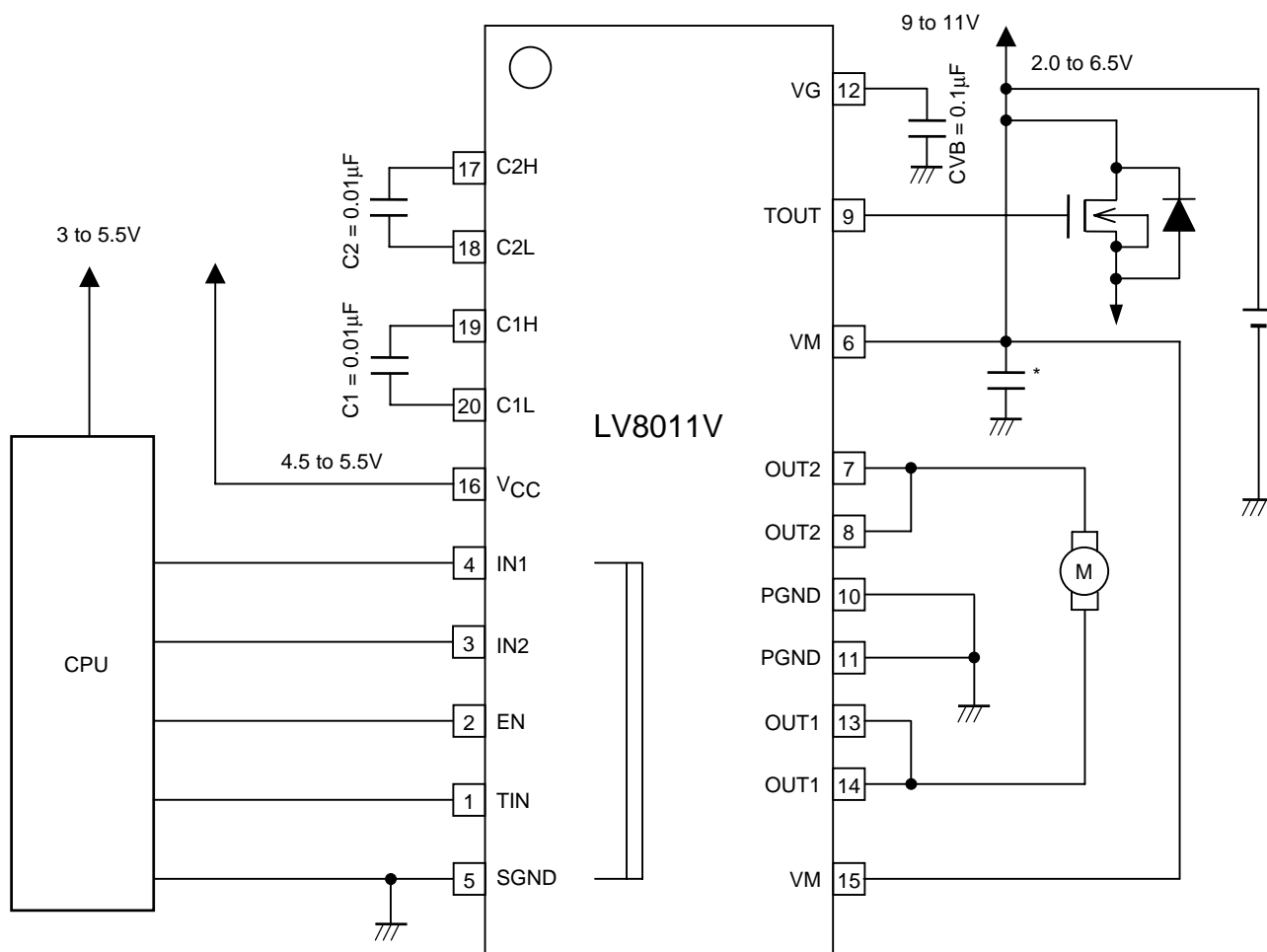
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Pin no.	Pin name	Equivalent Circuit	Pin Explanation
9	TOUT		Step-up Voltage Output Pin
6 15	VM		Driver Power Source (Both 2 pins are Connected.)
16	V <sub>CC</sub>		Logic Power Source
12	VG		Driving Circuit Unit Power Source for Driver
5	SGND		Logic GND
10 11	PGND		Driver GND (Both 2 pins are Connected.)

## Application Circuit Diagram



\* Place it as close as possible to VM and PGND pins of IC.

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## LV8011V

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